

## Surface Mount Superfast Recovery Rectifier

Reverse Voltage – 50 to 600 V    Forward Current –2 A

### FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Superfast reverse recovery time
- Lead free in comply with EU RoHS 2011/65/EU directives

### MECHANICAL DATA

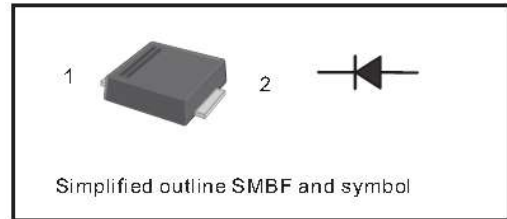
- Case: SMBF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 57mg / 0.002oz

### Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

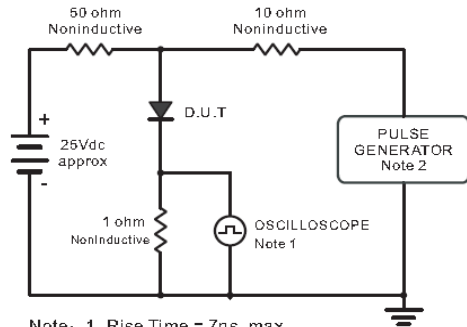


Parameter	Symbols	ES2ABF	ES2BBF	ES2CBF	ES2DBF	ES2EBF	ES2GBF	ES2JBF	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	600	V
Maximum RMS voltage	$V_{RMS}$	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current at $T_L = 100\text{ }^\circ\text{C}$	$I_{F(AV)}$	2							A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	$I_{FSM}$	50							A
Maximum Forward Voltage at 2A	$V_F$	1				1.25		1.65	V
Maximum DC Reverse Current at Rated DC Blocking Voltage $T_a = 25\text{ }^\circ\text{C}$ $T_a = 125\text{ }^\circ\text{C}$	$I_R$	5 100							$\mu\text{A}$
Typical Junction Capacitance at $V_R = 4\text{V}$ , $f = 1\text{MHz}$	$C_j$	45							pF
Maximum Reverse Recovery Time at $I_F = 0.5\text{A}$ , $I_R = 1\text{A}$ , $I_{rr} = 0.25\text{A}$	$t_{rr}$	35							ns
Typical Thermal Resistance <sup>2)</sup>	$R_{\theta JA}$	65							$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{stg}$	-55 ~ +150							$^\circ\text{C}$

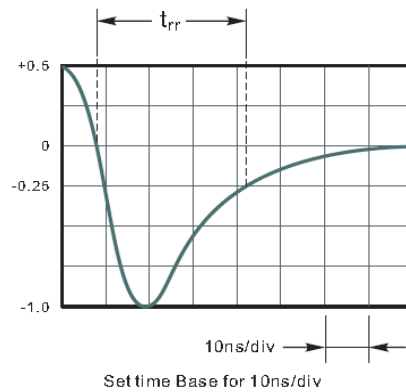
1) Measured with  $I_F = 0.5\text{ A}$ ,  $I_R = 1\text{ A}$ ,  $I_{rr} = 0.25\text{ A}$

2) P.C.B. mounted with 0.5 X 0.5" (12.7 X 12.7 mm) copper pad areas.

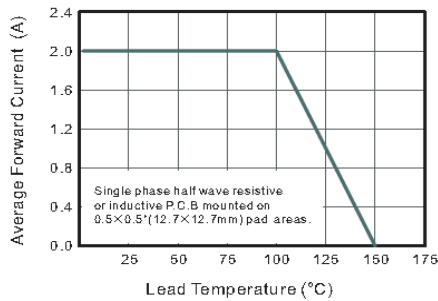
**Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram**



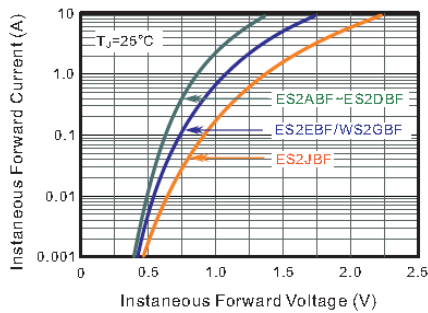
Note: 1. Rise Time = 7ns, max.  
Input Impedance = 1 megohm, 22pF.  
2. Rise Time = 10ns, max.  
Source Impedance = 50 ohms.



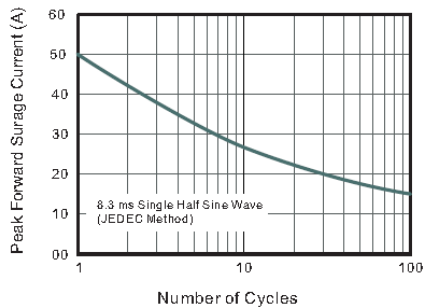
**Fig.2 Maximum Average Forward Current Rating**



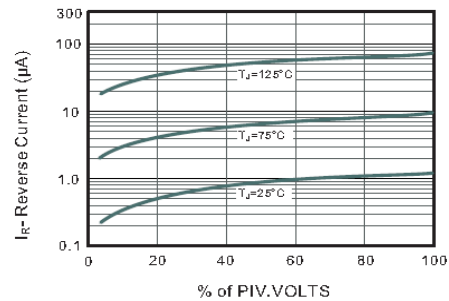
**Fig.4 Typical Forward Characteristics**



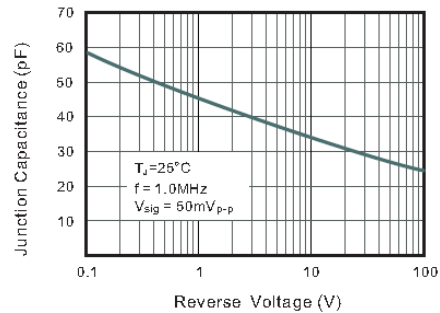
**Fig.6 Maximum Non-Repetitive Peak Forward Surge Current**



**Fig.3 Typical Reverse Characteristics**



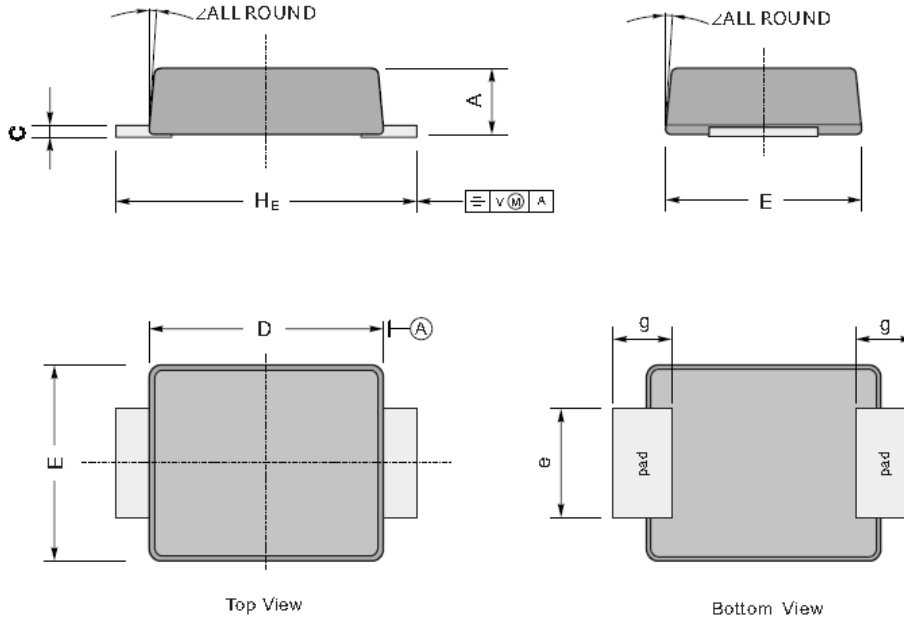
**Fig.5 Typical Junction Capacitance**



## PACKAGE OUTLINE

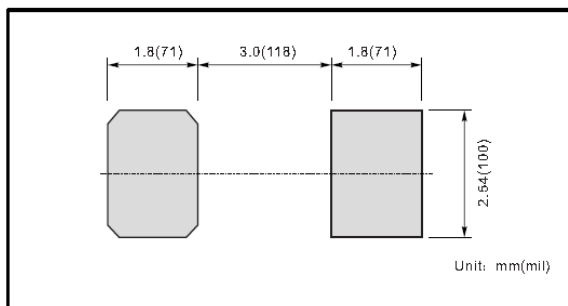
Plastic surface mounted package; 2 leads

SMBF



UNIT		A	C	D	E	$H_E$	e	g	$\angle$
mm	max	1.3	0.26	4.4	3.7	5.5	2.2	1.0	9°
	min	1.1	0.18	4.2	3.5	5.1	1.9		
mil	max	51	10	173	146	216	86	40	
	min	43	7	165	138	200	75		

### The recommended mounting pad size



### Marking

Type number	Marking code
ES2ABF	E2AB
ES2BBF	E2BB
ES2CBF	E2CB
ES2DBF	E2DB
ES2EBF	E2EB
ES2GBF	E2GB
ES2JBF	E2JB